



M T B F (E I A J R C R - 9 1 0 2)

Model	DHS50A12
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No.	P a r t s		Q'ty of Device	Failure rate [10 ⁻⁶ /H]	R e f e r e n c e
1	I C	Monolithic	2	0.0650	
2		Hybrid	0	0.0000	
3	Transistors		13	0.3080	
4	Diodes		27	0.4640	
5	LED•Optocouplers		2	0.1400	
6	Resistors		84	0.4364	
7	Capacitors		41	0.2664	
8	Transformer•Choke Coil		3	0.0690	
9	Connectors		63	0.1400	
10	Others		2	0.1130	
Total Failure Rate [10 ⁻⁶ /H]				2.0018	

M T B F [H]	500,000
Ambient Temperature [°C]	—
Load Factor [%]	—